Resonant Metagratings for Spectral and Angular Control of Light for Colored Rooftop Photovoltaics

Floris Uleman, Verena Neder,* Andrea Cordaro, Andrea Alù, and Albert Polman

ABSTRACT: We designed semitransparent metagrating supercells that enable control over the spectrum and directivity of incident light for applications in photovoltaics with tailored angular appearance. The building block of the supercells is a 100−120 nm wide and 175 nm tall silicon nanowire that shows a strong Mie resonance around $\lambda = 650$ nm. By arranging the resonant Mie scatterers into metagratings of increasing pitch (675−1300 nm), we created a Lambertian-like scattering distribution over an angular range of choice. The millimeter-sized metasurfaces were fabricated using electron beam lithography and reactive ion etching. The fabricated metasurface nearly fully suppresses specular reflection on resonance while 10% of the incoming light around the resonance is scattered into the angular range between 30° and 75°, creating a bright red appearance over this specific range of angles. Off-resonant light in the blue, green, and near-infrared is efficiently transmitted through the metasurface and absorbed in the underlying photovoltaic cell. The implemented silicon heterojunction solar cells with integrated metagrating supercells shows a reduction in external quantum efficiency matching the resonant scattering spectral range. The short circuit current is reduced by 13% due to the combined effects of resonant scattering, reflection from the high-index substrate, and absorption in the Si nanowires. In addition to efficient colorful photovoltaics with tailored angular appearance, the metagrating concept can find application in many other light management designs for photovoltaics and other optoelectronic devices.

KEYWORDS: colored photovoltaics, BIPV, transparent metagratings, metasurface, light management, solar cells, silicon nanoparticles, Mie resonators

1. INTRODUCTION

New solar power conversion architectures are increasingly important to achieve large-scale sustainable power generation to sustain the growing energy needs of our society. Integration of photovoltaics (PVs) into the local architecture, buildings, and urban terrains is a rapidly growing research and technology area and will be crucial to meet the requirements set by the Paris agreement in the coming years. Current commercial solar cells and modules typically have a blue or black color that does not always fit within the urban design. Modules with tailored color are necessary to integrate PVs into residential and modern city building architecture, where aesthetics plays a key role. In order to achieve both functional beauty and high power conversion efficiency, it is essential to develop innovative PV solutions to create colored solar cells while maintaining high efficiencies.

Over the past decades, research has shown different approaches to achieve colored PVs. Interference coatings and Bragg reflectors have been used to modify the reflected spectrum but do not offer control over the angular scattering. Colored optical coatings, based on polymer or luminescent materials, have been applied on the front module of cells but are often limited by absorption in the coating material. Other solutions, specifically for solar roof tiles, have been offered to control the field of view with louver films that shade the cells on a rooftop for observers from the ground. This simple approach shows esthetical results; however, the performance of the solar cell is highly restricted if the sun shines at a low angle, because the louver film also shades the sunlight. Scattering from plasmonic nanostructures has been applied in colorful solar cells but suffer from fundamental optical losses in the metal. Similarly, resonant dielectric nanoparticles have been used for spectrally controlled light scattering with minimal optical losses. Recently, these nanostructures have been employed for the creation of colorful solar cells, with the advantage of very little loss and scalable fabrication possibilities.
So far, few of the proposed designs for colored PVs exhibit both angular and spectral control on the reflected light. The possibility of designing the scattering angular profile at will is particularly appealing in colored PV applications for two main reasons: First, for a colored surface to appear matte, its angular reflectance has to follow the Lambertian cosine law (i.e., the apparent brightness of the scattered light should be the same for an observer from every angle). Second, it is important to reflect the color to a specific field of view of choice in order to minimize the losses as much as possible. The most obvious example is the application of directional colored solar cells on rooftops, where a red color appearance should be seen only from an observer near the building, while reflection upward is undesired.

The use of scattering dielectric nanoparticles allows controlling not only the spectrum, by exciting Mie resonances, but also the directivity by smartly arranging the scatterers into a metasurface. In previous studies, different metasurfaces, specifically metagratings, have been introduced to allow directional control of resonant reflection.22−29

In this work, we demonstrate how the geometry of an array of dielectric Mie scatterers arranged in a grating structure can be tailored such that light in a narrow spectral band is scattered over a well-defined angular range. To this end, we designed a supercell of multiple metagratings consisting of dielectric nanoparticles that show Lambertian resonant scattering while the nonresonant spectral bands are effectively transmitted. We demonstrate these concepts in a one-dimensional geometry employing Mie resonances in subwavelength silicon nanowires (NWs) that allow us to gain spectral control over the reflected light for one polarization direction; the design can be readily expanded to two dimensions.

The scattering resonances are tuned by optimizing the shape and spatial dimensions of the nanowires such that the scattering profile matches the desired scattering spectrum. We demonstrate resonant scattering around \( \lambda = 650 \) nm, yielding a red scattering profile. Next, the NWs are placed in multiple gratings on a transparent substrate that scatter light with a tailored distribution over the first diffraction orders. We apply the metasurface onto a Si solar cell and demonstrate that effective light scattering in a narrow spectral and angular band is combined with high external quantum efficiency of the solar cell.

2. THEORY AND DESIGN

In this section, we introduce the concept of a Mie-resonant metagrating and outline how to leverage its properties to tailor the spectral and angular response of the metasurface. Specifically, for rooftop PV applications, we design the response to correspond to a Lambertian angular profile spectrally peaked in the red portion of the visible spectrum. Different from previous approaches,27 the Mie resonators are placed on a transparent substrate such that only the resonant
portion of the spectrum is reflected, while the transmitted light can be conveniently collected by a solar cell (see Figure 1a). Upon excitation of Mie resonances, high-index dielectric nanoantennas can strongly scatter the incoming light.3,30,31 In particular, here we exploit the modes sustained by NWs made of silicon, taking advantage of its high refractive index. The scatterers are Si NWs of height $h = 175$ nm and width $w = 100−120$ nm on a sapphire substrate. The resonant wavelength of modes supported by such a high-index scatterer can easily be tuned by changing the size of the scatterer, thus enabling spectral control. Details about the scattering cross section of the single Si NW are given in the SI. In this work, the metasurface is designed to scatter light within a narrow bandwidth around $\lambda = 650$ nm.

Next, the Mie scatterers are placed into an array with periodicity $p$, such that first-order diffraction in air occurs while the second order is still evanescent. This is the case for periodicities in the range $650 \text{ nm} < p < 1300 \text{ nm}$, according to the grating equation for normally incident light $p \sin \theta_m = m \lambda$, where $\theta_m$ is the angle at which light is diffracted, $m$ is an integer denoting the order of diffraction, and $\lambda$ is the wavelength of the incident light. In this work, as light is normally incident on the grating, two symmetric first $(+1$ and $-1)$ diffraction orders exist that we refer to as first orders from now on. Figure 1b shows the simulated reflectance spectrum of a single grating with pitch $p = 900$ nm, where the unit cell is composed of a single Si NW ($w = 110$ nm, $h = 175$ nm) on sapphire, and it is illuminated at normal incidence by a plane wave polarized perpendicular to the NW (TE polarized). The reflectance into the zeroth and the $\pm 1$st diffraction orders ($\theta_m = \pm 46.2^\circ$ at $\lambda = 650$ nm) reveals three important features. First, a clear peak around the design wavelength $\lambda = 650$ nm ($\sim 20\%$) is observed due to resonant excitation of the modes of the Si NWs around this wavelength. Second, another peak around $\lambda = 410$ nm is observed ($\sim 15\%$), originating from a higher-order mode excitation. Third, a significant portion of the green and blue spectral range is directly reflected off the sapphire substrate to the zeroth order ($\sim 10\%$). It is important to note that most of the reflected light around the resonance is scattered into the first orders ($\sim 20\%$), while reflection back to the zeroth order is suppressed ($\sim 2\%$). In order to investigate the physical mechanism behind the suppression of specular reflection, we use the total-field-scattered-field method.34 Light resonantly scattered by the NWs interferes destructively with light reflected off the bare sapphire substrate, hence resulting in a suppressed reflection to the zeroth order. For destructive interference to arise, the amplitude of the reflected light from the substrate and that scattered by the NWs is designed to be equal, while the phase is shifted by $\pi$. This cancellation phenomenon is outlined in Figure 1c by investigating the scattered fields of the two scenarios. The field scattered by a single NW (left) and the one reflected by the sapphire substrate (right) are shown, when illuminated at normal incidence by a plane wave at $\lambda = 650$ nm (TE). In the first case, the total-field-scattered-field approach allows one to look only at the scattering contribution of the NW, and not of the substrate. Importantly, only the upward scattering in the specular direction is shown here. The outgoing specular reflected field from the bare sapphire substrate shows a clear phase shift compared to the scattered field of the NW. In addition, the phasor representation at a position in the upward scattering direction of the scattered (NWs) and reflected (bare sapphire) fields is shown for $\lambda = 650$ nm. In the complex plane, the electric field of the scattered light is depicted for both scenarios and allows a precise comparison of the amplitude (length of arrow) and phase (angle in complex plane). For the NW scenario, the amplitude was taken from the scattered wavefront of an array of NWs (pitch $p = 900$ nm), as the amplitude of a single NW is decreasing radially. The phase of the scattered field in the backward direction is equal for a single NW or a NW array. Notably, it can be seen that the phase shift is almost $\pi$ while the amplitude is close to equal at the wavelength of cancellation. The sum of the two vectors (black vector) shows that the cancellation is close to ideal. The reflection from the substrate is thus fundamental to achieve the cancellation in specular direction as discussed in more detail in the Supporting Information and also explained in ref 29.

By considering different pitches, each targeting a different outgoing angle of diffraction, and suitably combining them into a larger supercell, it is possible to design a prescribed overall angular response. A schematic overview of the design, resulting in a supercell that scatters from $30^\circ$ to $75^\circ$ for $\lambda = 650$ nm (pitch: $675−1300$ nm), is presented in the bottom of Figure 1a.

In colored PV applications, it is important that a Lambertian reflected angular profile is achieved to perceive a matte appearance.19 However, in rooftop PV applications, this requirement can be relaxed since the metasurface should appear Lambertian red only from an observer on the street. Hence, assuming that the sun is incident normal to the solar cells on a rooftop, we can disregard small diffracted angles in the design. Since common house roofs have an angle of $\sim 40^\circ$, the desired angular span of the designed angular response lies in the range $30^\circ−75^\circ$. Indeed, sunlight that hits the panel perpendicular is scattered toward the field of view of observers on the street. As mentioned before, the overall structure is realized by placing multiple metagratings next to each other, creating a “supercell” array of silicon nanowires with varying periodicities (see Figure 1a). Within this procedure, it is also important to take into account the relative area of each metagrating (adjusted by their own efficiencies) in order to properly reproduce the Lambertian intensity distribution in reflection. The total area of the supercell is the sum of all grating areas, and it adds up to $223 \mu$m. The specific values of $p$, $w$, the total reflection and reflection to the first order for individual metagratings, and the number of unit cells used in each of the metagratings composing the supercell are summarized in Table S1.

3. EXPERIMENTS

In order to experimentally demonstrate the possibility of gaining angular and spectral control via transparent metagratings, we fabricated the structure described above and characterized it optically. Next, we compare the measured data to numerical simulations and assess the performance of a solar cell with the optimized metasurface integrated into its structure.

3.1. Fabrication. The metagratings were fabricated using electron beam lithography (EBL), as described in the following. First, silicon-on-sapphire substrates (500 nm c-Si on 0.46 mm R-plane sapphire, MTI Corporation) were cleaned in base piranha. The silicon layer is etched down to a thickness of $175$ nm using reactive ion etching (RIE) using a CHF3 (15 sccm)–SF6 (10 sccm)–O2 (3 sccm) plasma etch. Next, a $50−60$ nm HSQ high-resolution negative resist layer was spin-coated on the sample and baked for 150 s at $180 \; ^\circ\text{C}$. For better conductivity, Electra 92 (AR-PC-5091) was spin-coated on the sample. The substrate was then exposed using a Raith Voyager lithography system (dose of 2.400 $\mu$C/cm²). To obtain a sample that

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is large enough for optical measurements, the supercell of 223 \mu m described above is replicated 6 times next to each other, resulting in a 1.35 mm wide field. After e-beam writing, the sample was developed in TMAH for 75 s at 50 °C. The patterned HSQ is then used as a hard mask to structure the underlying Si layer using two subsequent RIE etching steps. First, the native oxide of the silicon is etched using Cl₂ (60 sccm), and then the silicon is etched in a HBr (48.6 sccm) and O₂ (1.4 sccm) plasma at 60 °C.

The result of the described fabrication is shown in Figure 2. The sample consists of silicon NWs with a remaining HSQ layer on top, on a sapphire substrate. A single NW is depicted in Figure 2a,b, showing that the side walls are etched perpendicular to the substrate. The HSQ on top of the nanowire is not removed as this process involves chemical reactions that also react with the sapphire substrate. For better resolution, a layer of Electra 92 (AR-PC-5091) was spin-coated on the sample before imaging. An overview SEM image of the total supercell is shown in Figure 2c. The pitch between the wires is decreasing from left (p = 1300 nm) to right (p = 675 nm), and for the complete area of the supercell, a good uniformity was achieved. On the right side of the supercell, the beginning of the next identical supercell is visible.

### 3.2. Optical Characterization.

To distinguish light reflected specularly (0th order) from light reflected at an angle (1st orders), we use an integrating sphere. We measure both the sample’s total reflectance and the total reflectance excluding the zeroth order. The difference between the two measurements then yields the zeroth-order reflectance (see Supporting Information for a schematic of the setup).

Figure 3a shows the measured specular reflectance spectrum, as well as the total reflectance spectrum excluding the specular contribution, which we refer to as the scattered spectrum. The latter shows a broad peak centered at \( \lambda = 614 \text{ nm} \) reaching 9.9% reflectance. The full width at half-maximum of this peak is around 200 nm, covering the wavelength range of interest for red color perception. At the same time, in the same bandwidth around \( \lambda = 614 \text{ nm} \), the zeroth-order reflectance is strongly suppressed, as desired. Indeed, the zeroth-order reflectance is around 8% in the blue wavelength range and decreases to 2% on resonance demonstrating efficient light redirection. Additionally, the reflection at wavelengths above the resonance is slightly decreased.

Figure 3b shows simulated scattered and specular reflectance spectra. The experimentally measured trends show good agreement with the simulated spectra: a broad peak around 680 nm in the averaged first-order reflection (average reflectance to first orders: sum of the reflectance from the different metagratings composing the metasurface, weighted by their relative area) corresponds to a clear reduction in specular reflection. The peak position can be explained by the combined contributions of the different metagratings (see SI). We ascribe the lower measured reflectance compared to the simulations to fabrication imperfections resulting in silicon NWs with slightly different dimensions, as well as small slanting of the sidewalls which results in a less pronounced resonance.

Figure 4a shows the angular reflectance as a function of wavelength, measured using a rotating stage setup (see ref29 for the description of measurement setup). The measurements were performed in the wavelength range \( \lambda = 550–700 \text{ nm} \) in steps of 10 nm. First of all, as designed, the sample does not scatter light to angles below 30° and above 75°. As mentioned earlier, the design is optimized to have only the first diffraction orders at \( \lambda \geq 650 \text{ nm} \). This can be observed in the measured spectra (Figure 4a). For shorter wavelengths \( \lambda \leq 650 \text{ nm} \), second-order diffraction in reflection is noticeable at high angles. Furthermore, following the grating equation, the diffraction angle for each metagrating increases as the illumination wavelength increases. The measurement significantly reflects very similar features in the simulated angular reflectance spectra in Figure 4b.

Figure 4c shows the measured angular reflectance at \( \lambda = 650 \text{ nm} \). The scattered part of the light is depicted in red, whereas the gray dashed line represents the ideal Lambertian cosine distribution. Experimentally, the angular reflectance follows the desired cosine law rather well for angles in the range 30°–75°. The two high-reflection peaks at 45° are the result of a nonideal design; they are also visible in simulations (see Figure 4d and Table S1). The blue part of the
angular reflectance represents the zeroth-order reflection and peaks at 6.8%/deg and 3.0%/deg in experiment and simulations, respectively (out of scale in Figure 4c,d). We observe a broader reflection range for the zeroth-order peak in the measurement compared to that in simulation, due to a difference in binning (0.18° in simulation versus 1.0° in measurement). Overall, we conclude that the experimental results follow the simulation results with good agreement.

3.3. Electrical Characterization. Next, we apply the transparent metagrating on a Si solar cell. The nanopatterned sapphire substrate was placed on top of a heterojunction silicon solar cell using immersion oil (Fluka 10976, n = 1.52) (same setup as in ref 19). The cell features a textured front surface and a standard antireflection coating. We measured the external quantum efficiency (EQE) for three different cases: bare solar cell, cell with clean sapphire substrate, and cell with the fabricated metagrating sample (see Figure 5). With the sapphire substrate in place, we observe a similar trend as for the bare silicon solar cell, with slightly lower EQE over the whole spectrum. The reduction in EQE is due to reflection of light from the front surface of the sapphire, which is around 8% over the visible wavelength range. The EQE of the cell with the metagrating sample on top is lower compared to the EQE of the cell with sapphire, especially below λ = 800 nm. A closer inspection of the spectrum shows a reduction of the EQE from λ = 600–800 nm, which is due to the as-designed enhanced reflection shown in Figure 3a. The inset in Figure 5 shows a photo taken under 45° of the sample placed on top of the solar cell. The bright red rooftop-like colored reflection is clearly visible.

In the lower-wavelength range, the EQE is reduced due to the higher absorption in the silicon nanowires. This could potentially be reduced by replacing the silicon with a material with a lower absorption in the visible range (e.g., TiO₂). The measured short circuit current density for the bare silicon solar cell is Jsc = 38.9 mA/cm². Including the metagrating sample on top slightly reduces the value to Jsc = 34.0 mA/cm². This implies that to the first order the cell efficiency is reduced by relatively 13% due to the narrow-angle colored scattering metasurface.

4. CONCLUSION

In this work, we experimentally demonstrated spectral and angular control of scattered light using resonant metagratings...
for colored photovoltaics. Silicon nanowires were fabricated on a transparent substrate and resonantly scatter light around $\lambda = 650$ nm. The nanowires were placed in a supercell structure composed of multiple gratings with different pitches, creating a Lambertian scattering distribution with specular reflection that is nearly fully suppressed and efficient transmission outside the resonant scattering band. The supercell structure was designed to backscatter light within the 30–75° range, and experiments and simulations are in very good agreement. The metagratings are integrated with a silicon heterojunction solar cell creating a bright red scattering appearance under a limited range of angles, as desired, and enable seamless integration with roof tile geometries. The external quantum efficiency is only reduced in the scattering spectral band, with a short circuit current drop of only 13%. Future asymmetric designs may further enhance the efficiency by scattering light only to the ground and not to the sky. The nanopatterned geometries presented here can be readily fabricated and up-scaled to practical PV applications. The sapphire substrate can be replaced by solar panel module glass, and the crystalline Si Mie scatterers can be replaced by other high-index materials such as amorphous Si and TiO$_2$, the latter potentially also via a sol-gel route. The SCIL technique$^1$ used here is already being developed into a large-scale fabrication technique using a cassette-based wafer handling while a roll-to-roll soft imprint is also widely being developed. Furthermore, tailored spray coating techniques could also be employed to create arrays of nanoparticles.

**ASSOCIATED CONTENT**

The Supporting Information is available free of charge at https://pubs.acs.org/doi/10.1021/acsaem.0c00027. Scattering spectrum of Si NW, metagrating efficiency, parameter overview, period dependence of metagrating reflectance, analysis of angle of incidence, and integrating sphere measurement setup (PDF)

**AUTHOR INFORMATION**

Corresponding Author

Verena Neder – Institute of Physics, University of Amsterdam, 1098 XH Amsterdam, The Netherlands; Center for Nanophotonics, NWO-Institute AMOLF, 1098 XG Amsterdam, The Netherlands; orcid.org/0000-0003-0460-391X; Email: v.neder@amolf.nl

Authors

Floris Uelman – Institute of Physics, University of Amsterdam, 1098 XH Amsterdam, The Netherlands; Center for Nanophotonics, NWO-Institute AMOLF, 1098 XG Amsterdam, The Netherlands

Andrea Cordaro – Institute of Physics, University of Amsterdam, 1098 XH Amsterdam, The Netherlands; Center for Nanophotonics, NWO-Institute AMOLF, 1098 XG Amsterdam, The Netherlands; orcid.org/0000-0003-3000-7943

Andrea Alù – Photonics Initiative, Advanced Science Research Center, City University of New York, New York, New York 10031, United States

Albert Polman – Center for Nanophotonics, NWO-Institute AMOLF, 1098 XG Amsterdam, The Netherlands; orcid.org/0000-0002-0685-3886

Complete contact information is available at: https://pubs.acs.org/10.1021/acsaem.0c00027

**Notes**

The authors declare no competing financial interest.

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